

WSJM65R170 Super-Junction Power MOSFET Rev.01 - 20 February 2024

Product data sheet

1. General description

WSJM65R170 is a high voltage N-channel MOSFET in TO220 package, which utilizes the advanced super-junction technology to provide superior FOM $R_{DS(on)} * Q_g$ among silicon based MOSFETs. It is particularly suitable for applications require extreme high efficiency and power density.



2. Features and benefits

- Superior FOM $R_{DS(on)} * Q_g$
- Extremely low switching loss
- 100% avalanche tested

3. Applications

high efficiency power supplies

4. Quick reference data

Table 1. Qu	lick reference data						
Symbol	Parameter	Conditions	Notes	Values		Unit	
Absolute	maximum rating						
V _{DS}	drain-source voltage				650		V
V_{GS}	gate-source voltage				±30		V
I _D	continuous drain current	T _{mb} = 25 °C		23		А	
P _{tot}	power dissipation	T _{mb} = 25 °C		240		W	
T _j	junction temperature			-55 to 150		°C	
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics						
$R_{\text{DS(on)}}$	drain-source on-state resistance	V _{GS} = 10 V, I _D = 11 A		-	156	170	mΩ
Dynamic of	characteristics	·			·	·	·
Q _{G(tot)}	total gate charge	I_{D} = 11 A; V_{DS} = 400 V; V_{GS} = 10 V		-	38	-	nC
E _{oss}	coss stored erergy	V_{GS} = 0 V; V_{DS} = 0 to 400 V		-	5.1	-	μJ

5. Pinning information

Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol			
1	G	gate	mb	P			
2	D	drain	$2 \sim 10^{-1}$	\square			
3	S	source					
mb	D	mounting base; connected to drain		svm300 S			

6. Ordering information

Table 3. Ordering information								
Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date		
WSJM65R170	TO220	WSJM65R170Q	Tube	50	SOT78	13-Jun-2008		

7. Marking

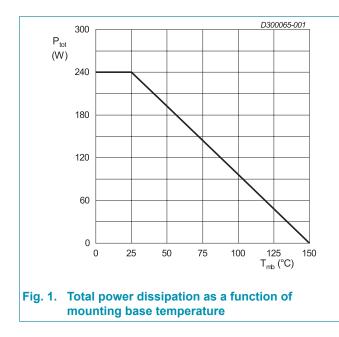
Table 4. Marking codes	
Type number	Marking codes
WSJM65R170	WSJM 65R170

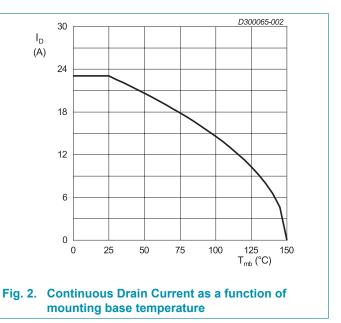
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V _{DS}	drain-source voltage			650	V
V _{GS}	gate-source voltage			±30	V
I _D	continuous drain current	T _{mb} = 25 °C		23	А
		T _{mb} = 100 °C		14	А
I _{DM}	pulsed drain current	T _{mb} = 25 °C		72	А
P _{tot}	power dissipation	T _{mb} = 25 °C		240	W
E _{AS}	single pulse drain-to- source avalanche	I_{AS} = 6.9 A; R _{GS} = 25 Ω; V _{DD} = 50 V; T _j = 25 °C		238	mJ
E _{AR}	repetitive avalanche energy	$I_{AS} = 6.9 \text{ A}; \text{ R}_{GS} = 25 \Omega; \text{ V}_{DD} = 50 \text{ V};$ $T_j = 25 \text{ °C}$		1.67	mJ
I _{AS}	avalanche current, single pulse			6.9	A
dv/dt	MOSFET dv/dt ruggedness			50	V/ns
dv/dt	reverse diode dv/dt			15	V/ns
dl _F /dt	maximum diode commutation speed			500	A/µs
T _{stg}	storage temperature			-55 to 150	°C
T _j	junction temperature			-55 to 150	°C

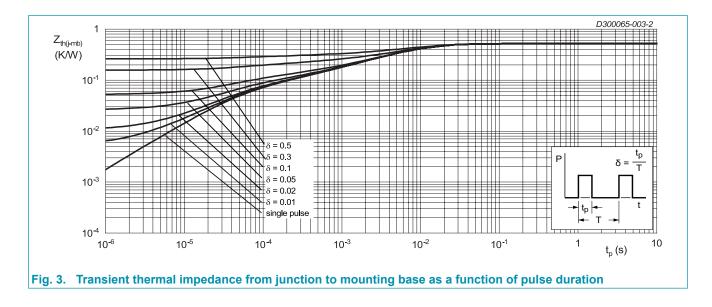




9. Thermal & Mechanical characteristics

Table 6. Thermal & Mechanical characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base			-	0.45	0.52	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air		-	60	-	K/W



10. Characteristics

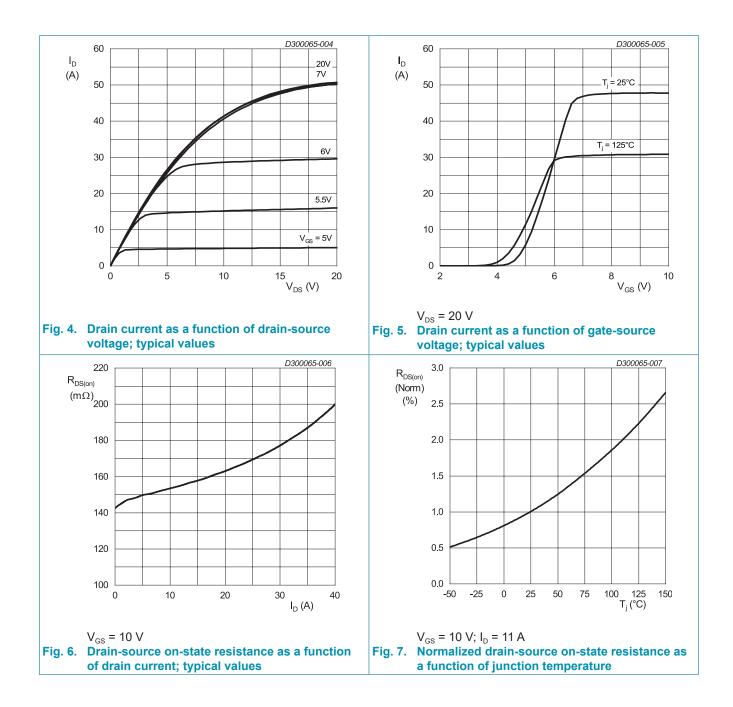
Table 7. Characteristics

T_j = 25 °C unless otherwise noted

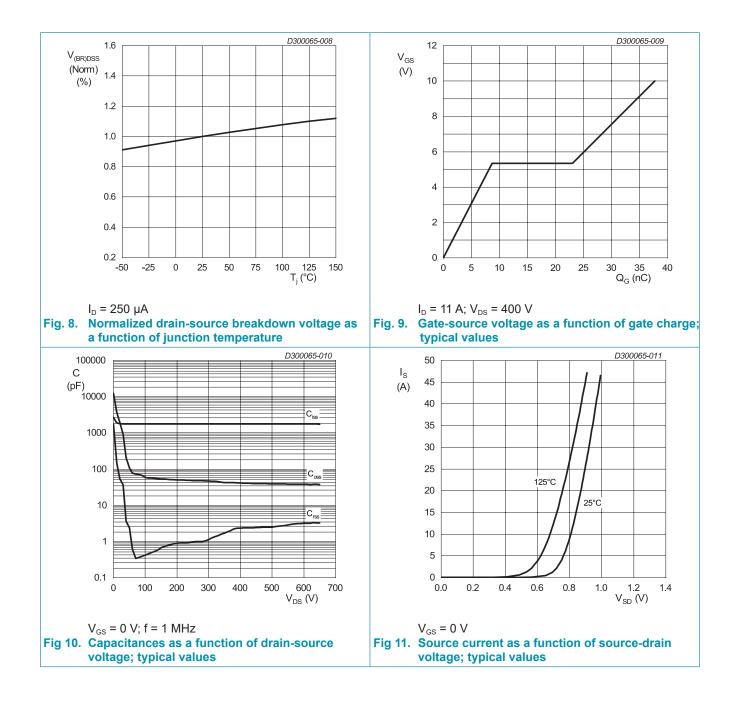
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics						
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_{\rm D}$ = 250 µA; $V_{\rm GS}$ = 0 V		650	-	-	V
$V_{\text{GS(th)}}$	gate-source threshold voltage	$I_{\rm D}$ = 250 µA; $V_{\rm DS}$ = $V_{\rm GS}$		2.5	-	4.5	V
I _{DSS}	drain leakage current	$V_{DS} = 650 \text{ V}; V_{GS} = 0 \text{ V}$		-	-	1	μA
		V_{DS} = 650 V; V_{GS} = 0 V; T_j = 125 °C		-	-	10	μA
I _{GSS}	gate leakage current	$V_{GS} = \pm 30 \text{ V}; V_{DS} = 0 \text{ V}$		-	-	±100	nA
$R_{\text{DS(on)}}$	drain-source on-state resistance	V _{GS} = 10 V; I _D = 11 A		-	156	170	mΩ
R _G	gate resistance	f = 1 MHz		-	12	-	Ω
Dynamic	characteristics						
Q _{G(tot)}	total gate charge	I_{D} = 11 A; V_{DS} = 400 V; V_{GS} = 10 V		-	38	-	nC
Q_{GS}	gate-source charge			-	8.7	-	nC
Q _{GD}	gate-drain charge			-	14	-	nC
C _{iss}	input capacitance	V _{DS} = 400 V; V _{GS} = 0 V; f = 1 MHz		-	1751	-	pF
C _{oss}	output capacitance			-	41	-	pF
C _{rss}	reverse transfer capacitance			-	2.3	-	pF
C _{o(er)}	effective output capacitance, energy related	V_{GS} = 0 V; V_{DS} = 0 to 400 V		-	64	-	pF
C _{o(tr)}	effective output capacitance, time related			-	370	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 400 \text{ V}; V_{GS} = 10 \text{ V}; \text{ R}_{G} = 2 \Omega;$		-	21	-	ns
t _r	rise time	I _D = 11 A		-	21	-	ns
$t_{d(off)}$	turn-off delay time			-	72	-	ns
t _f	fall time			-	11	-	ns
Source-d	rain diode						
V _{SD}	source-drain voltage	V _{GS} = 0 V; I _S = 11 A		-	0.8	1.1	V
ls	body-diode continuous current	T _{mb} = 25 °C		-	-	23	A
t _{rr}	reverse recovery time	V_{R} = 400 V; I _F = 11 A; dI _F /dt = 100 A/µs		-	285	-	ns
Q _{rr}	reverse recovered charge			-	3.8	-	μC
I _{rrm}	reverse recovery current			-	26	-	Α

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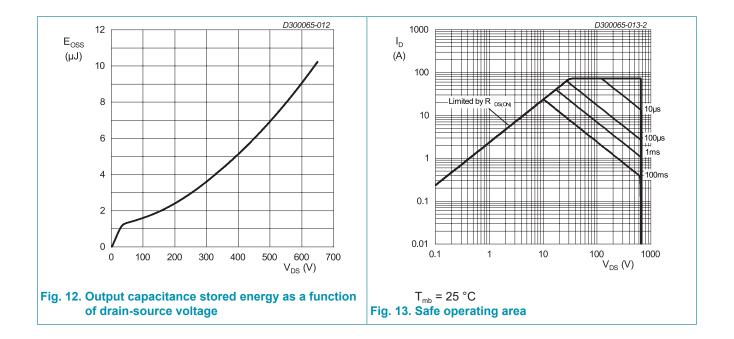
Super-Junction Power MOSFET



Super-Junction Power MOSFET

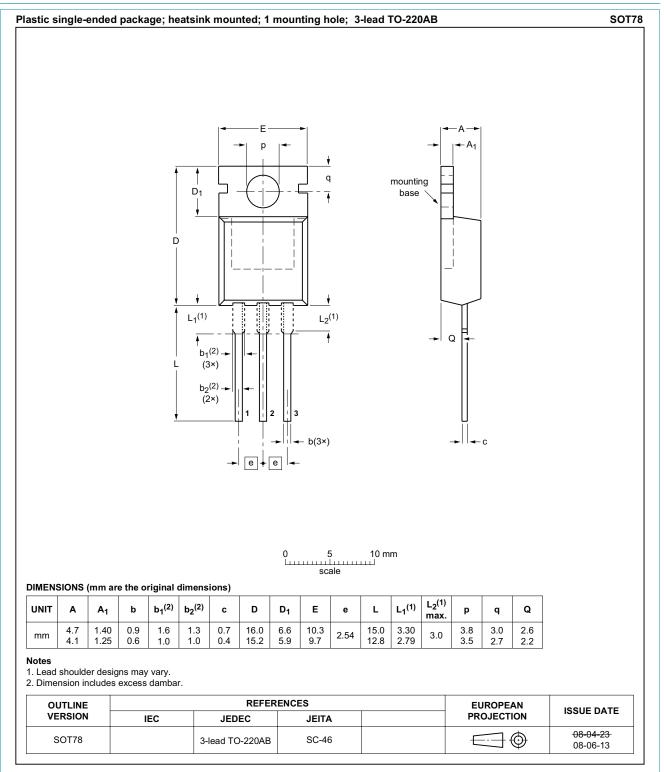


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WSJM65R170 Super-Junction Power MOSFET

11. Package outline



WSJM65R170

Super-Junction Power MOSFET

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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